

Single Driver for GaAs FET Switches and Attenuators

M/A-COM Products Rev. 6

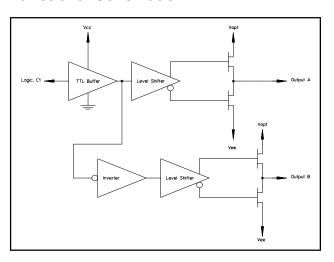
Features

- High Speed CMOS Technology
- Single Channel
- Positive Voltage Control
- Low Power Dissipation
- Low Cost Plastic SOIC-8 Package

Description

The SWD-109-PIN is a single channel driver used to translate TTL control inputs into gate control voltages for GaAs FET microwave switches and attenuators. High speed analog CMOS technology is utilized to achieve low power dissipation at moderate to high speeds, encompassing most microwave switching applications. The output HIGH level is optionally 0 to +2.0V (relative to GND) to optimize the intermodulation products of the control devices at low frequencies.

Functional Schematic



Ordering Information

Part Number	Package			
SWD-109-PIN	Bulk Packaging			
SWD-109TR	1000 piece reel			

Note: Reference Application Note M513 for reel size information.

Pin Configuration

Pin No.	Function
1	Output A
2	GND
3	Vcc
4	C1, Logic
5	Vee
6	Vopt
7	GND
8	Output B

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Guaranteed Operating Ranges

Symbol	Parameter ¹	Unit	Min.	Тур.	Max.
V _{cc}	Positive DC Supply Voltage	V	4.5	5.0	5.5
V _{EE}	Negative DC Supply Voltage	V	-8.5	-5.0	-4.5
V _{OPT} ²	Optional DC Output Supply Voltage	V	0	1.0	2.0
V _{OPT} -V _{EE}	Negative Supply Voltage Range	V	4.5	6.5	11.0
V _{CC} -V _{EE}	Positive to negative Supply Range	V	9.0	10.0	14.0
T _A	Operating Ambient temperature	°C	-40	+25	+85
I _{OH}	DC Output Current - High	mA	_	_	-1.0
I _{OL}	DC Output Current - Low	mA	_	_	1.0
T_{rise},T_{fall}	Maximum Input Rise or Fall Time	ns	_	_	500

^{1.} All voltages are relative to GND.

DC Characteristics over Guaranteed Operating Range

Symbol	Parameter	Test Co	nditions	Units	Min.	Тур.	Max.
V _{IH}	Input High Voltage	Guaranteed High Input Voltage		V	2.0	_	_
V _{IL}	Input Low Voltage	Guaranteed Lov	w Input Voltage	V	_	_	0.8
V _{IH}	Output High Voltage	I _{OH} = -1 mA	V _{EE} = Max	V	V _{OPT} -0.1	_	_
V _{OL}	Output Low Voltage	I _{OL} = 1 mA	V _{EE} = Max	V	_	_	V _{EE} +0.1
I _{IN}	Input Leakage Current	V _{IN} = V _{CC} or GND	V _{EE} = Min	μA	_	.01	10
I _{cc}	Quiescent Supply Current	V_{CC} = Max V_{OPT} = Min or Max	$V_{EE} = Min$ $V_{IN} = V_{CC} \text{ or GND}$	μA	_	_	100
ΔI _{CC}	Additional Supply Current, per TTL Input pin	V _{CC} = Max	V _{IN} = V _{CC} -2.1V	mA	_		1.0

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

volume is not guaranteed.

Silicon Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Truth Table

Input	Outputs				
C1	Α	В			
Logic "0"	V _{EE}	V _{OPT}			
Logic "1"	V _{OPT}	V _{EE}			

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^{2.} V_{OPT} is grounded for most applications. To improve the intermodulation performance and the 1 dB compression point of GaAs control devices at low frequencies, VOPT can be increased to between 1.0 and 2.0V. The nonlinear characteristics of the GaAs control devices will approximate performance at 500 MHz. It should be noted that the control current is on the GaAs MMICs will increase when positive controls are applied.

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AC Characteristics Over Guaranteed Operating Range³

Symbol	Parameter	-55 to +25°C	<u><</u> +85°C	<u><</u> +125°C	Unit
T _{PLH}	Propagation Delay	22	25	30	ns
T _{PHL}	Propagation Delay	22	25	30	ns
T _{TLH}	Output Rising Transition Time	9.0	9.0	9.0	ns
T _{THL}	Output Falling Transition Time	8.0	8.0	8.0	ns
T _{skew}	Delay Skew, Output A to Output B	4.0	4.0	4.0	ns
C _{IN}	Input Capacitance	10	10	10	pF
C _{PDC}	Power Dissipation Capacitance ⁴	10	10	10	pF
C _{PDE}	Power Dissipation Capacitance ⁴	140	140	140	pF

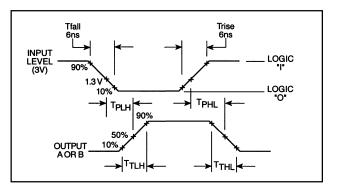
^{3.} V_{CC} = 4.5V, V_{OPT} - V_{EE} = min or max, V_{OPT} = 0V, C_L = 25 pF, Trise, Tfall = 6ns. These conditions represent the worst case for slow delays. 4. Total Power Dissipation is calculated by the following formula: PD = V_{CC} 2 fC $_{PDC}$ + $(V_{OPT}$ - $V_{EE})$ 2 fC $_{PDE}$

Absolute Maximum Ratings⁵

Symbol	Parameter	Min	Max	Unit
V _{CC}	Positive DC Supply Voltage	-0.5	7.0	V
V _{EE}	Negative DC Supply Voltage	-9.0	0.5	٧
V _{OPT}	Optional DC Output Supply Voltage	-0.5	Vcc +0.5	٧
V _{OPT} -V _{EE}	Output to Negative Supply Voltage Range	-0.5	11.0	٧
V _{CC} -V _{EE}	Positive to Negative Supply Voltage Range	-0.5	14.0	٧
Vı	DC Input Voltage	-0.5	V _{CC} +0.5	٧
I _I	DC Input Current	-25	25	mA
Vo	DC Output Voltage	V _{EE} – 0.5	V _{OPT} +0.5	٧
P _D ⁶	Power Dissipation in Still Air	1	500	mW
Vo	DC Output Current	-25	25	mA
T _{STG}	Storage Temperature	-65	150	°C

All voltages are referenced to GND. All inputs and outputs incorporate latch-up protection structures.

Switching Waveforms



Derate -7 mW/°C from 65°C to 85°C.

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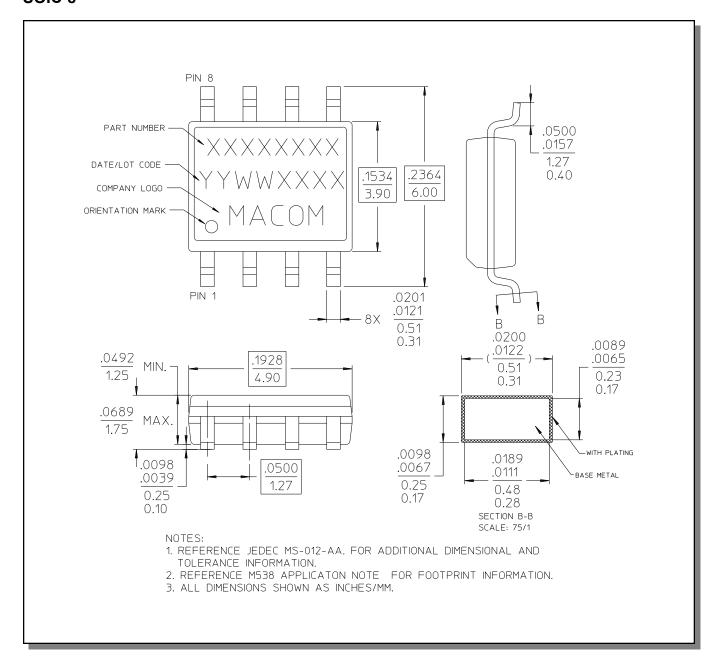
SWD-109-PIN



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SOIC-8[†]



[†] Reference Application Note M538 for lead-free solder reflow recommendations.

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not quaranteed.

ADVANCED: Data Sheets contain information regarding a product M/A-COM is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.

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